



2812

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent Application of)

Shunpei YAMAZAKI et al.)

Serial No. 09/362,192)

Filed: July 28, 1999) Group Art Unit: 2812

For: SEMICONDUCTOR DEVICE) Examiner: V. Simkovic

HAVING SEMICONDUCTOR)

CIRCUIT COMPRISING)

SEMICONDUCTOR ELEMENT)

AND METHOD FOR)

MANUFACTURING THE SAME)

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AMENDMENT AND RESPONSE TO ELECTION REQUIREMENT

Honorable Commissioner for Patents

Washington, D.C. 20231

Sir:

In response to the Office Action of March 16, 2001, please amend the subject application as follows:

IN THE CLAIMS:

Cancel claims 29-44 without prejudice to applicants' right to file a division application with respect thereto.

Please amend claim 52 as follows:

Sub C27
~~52. (Amended) A method for manufacturing a semiconductor device comprising steps of:~~

~~contacting a material for promoting crystallization to at least a part of an initial semiconductor film formed over a substrate;~~

~~subjecting said semiconductor film to oxygen plasma; and~~

~~crystallizing said initial semiconductor film using said material, to obtain a crystalline semiconductor film.~~

Please add new claims 60-66 as follows: